L Number	Hits	Search Text	DB	Time stamp
1	3		USPAT;	2002/02/07 14:00
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	20	//UCOC1701U) /UCOC0040U) /UCOC5	IBM TDB	
2	32	, , , , , , , , , , , , , , , , , , , ,		2002/02/07 14:57
		or ("6051468") or ("6015737") or ("5897343") or ("5776812") or ("5021355")	US-PGPUB;	
		or ("4983535") or ("5861649") or	EPO; JPO;	
		("5877528") or ("6072214") or	DERWENT; IBM TDB	
		("5502320")).PN.	IBM IDD	
3	13	(("6221721") or ("6069043") or ("6051488")	USPAT	2002/02/07 16:06
		or ("6051468") or ("6015737") or		
		("5897343") or ("5776812") or ("5021355")		
		or ("4983535") or ("5861649") or		
		("5877528") or ("6072214") or		
	2	("5502320")).PN.		
5	0	(("5502320") or ("5986304")).PN.	USPAT	2002/02/07 16:07
	0	("common adj source and trench adj gate").PN.	USPAT	2002/02/07 16:07
6	36	common adj source and trench adj gate	HCDAM.	2002/02/07 16 00
	30	common adj source and crench adj gate	USPAT;	2002/02/07 16:08
2			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	0	257/\$5.ccls. and breakdown and avalanche	USPAT;	2002/02/07 14:00
		and low adj on adj resistance	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	^	257/\$5 colo and handledown and law al'	IBM TDB	
_	U	257/\$5.ccls. and breakdown and low adj on	USPAT;	2001/10/01 07:58
		adj resistance	US-PGPUB;	
, , , , , , , , , , , , , , , , , , ,			EPO; JPO; DERWENT;	
			IBM TDB	
-	321	257/\$5.ccls. and breakdown and low adj2	USPAT;	2001/10/01 07:59
		resistance and latch\$3	US-PGPUB;	1002/20/02 01:05
			EPO; JPO;	
			DERWENT;	
	4 6-	057/05	IBM TDB	
_	15	The second secon	USPAT;	2001/10/01 07:59
		resistance and latch\$3 and avalanche and trench	US-PGPUB;	
		CIGNON	EPO; JPO;	
:			DERWENT; IBM TDB	
-	15	257/\$5.ccls. and breakdown and low adj2	USPAT;	2001/10/01 08:10
	_	resistance and latch\$3 and avalanche and	US-PGPUB;	2001/10/01 00.10
		trench and power	EPO; JPO;	
			DERWENT;	
	_	/OFB /AF	IBM TDB	
_	0	(257/\$5.ccls. and breakdown and low adj2	USPAT;	2001/10/01 08:00
		resistance and latch\$3 and avalanche and	US-PGPUB;	
		trench and power) and hamada.in.	EPO; JPO;	
			DERWENT; IBM TDB	
_	8	257/\$5.ccls. and breakdown and low adj2	USPAT;	2001/10/01 08:35
		resistance and latch\$3 and avalanche and	US-PGPUB;	2001/10/01 08:33
		trench and power and ight	EPO; JPO;	
	j	_ ~	DERWENT;	
			IBM TDB	
-	3	257/\$5.ccls. and breakdown and low adj2	USPAT;	2001/10/01 08:37
		resistance and latch\$3 and avalanche and	US-PGPUB;	
Lie china na n		trench and power and igbt and rie	EPO; JPO;	
	ļ		DERWENT;	
_	562	wortical manufact to	IBM TDB	0004440464
	302	vertical near4 mosfet.ti.	USPAT;	2001/10/01 13:15
	1		US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
I	<u> </u>		1 <i>DD</i>	

		vertical near4 mosfet.ti. and drift adj drain.ti,ab.	US-PGPUB;	2001/10/01 13:15
			EPO; JPO;	
			DERWENT;	
_	0	vertical near4 mosfet.ti. and drift adj2	IBM TDB USPAT;	2001/10/01 13:15
		drain	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
•••	7	vertical near4 mosfet.ti. and (drift near4	USPAT;	2001/10/01 13:15
		drain)	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	36	1	USPAT;	2001/10/01 16:53
	 	polyaniline	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	0	semiconducting adj polymer same polyaniline and 106/\$5.ccls.	USPAT; US-PGPUB;	2001/10/01 16:53
		p-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1	EPO; JPO;	
			DERWENT;	
_	356	("257/329").CCLS.	IBM TDB USPAT;	2002/02/01 13:33
		(2017 025 7.0025.	US-PGPUB;	2002/02/01 13.33
1			EPO; JPO;	
			DERWENT; IBM TDB	
_	568	("257/330").CCLS.	USPAT;	2002/02/01 13:33
			US-PGPUB;	·
			EPO; JPO;	
			DERWENT; IBM TDB	
_	280	("257/331").CCLS.	USPAT;	2002/02/01 13:33
			US-PGPUB; EPO; JPO;	
			DERWENT;	
	239	("257/332").CCLS.	IBM TDB	0000/00/01 10 00
	239	(237/332).CCLS.	USPAT; US-PGPUB;	2002/02/01 13:33
			EPO; JPO;	
			DERWENT; IBM TDB	
-	525	("257/341").CCLS.	USPAT;	2002/02/01 13:33
			US-PGPUB;	·
			EPO; JPO; DERWENT;	
			IBM TDB	
_	284	("257/342").CCLS.	USPAT;	2002/02/01 13:33
			US-PGPUB; EPO; JPO;	
			DERWENT;	
	1013	/ !! 257 / 401 !! \	IBM TDB	0000/00/00
_	1013	("257/401").CCLS.	USPAT; US-PGPUB;	2002/02/01 13:39
			EPO; JPO;	
			DERWENT;	
_	79	("257/135").CCLS.	IBM TDB USPAT;	2002/02/01 13:39
			US-PGPUB;	2002,02,01 13.39
			EPO; JPO;	
			DERWENT; IBM TDB	
_	124	("257/491").CCLS.	USPAT;	2002/02/01 13:39
			US-PGPUB;	
			EPO; JPO; DERWENT;	
. 1			IBM TDB	1

-	76	("257/492").CCLS.	USPAT;	2002/02/01 13:39
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	83	("257/402") CCI C	IBM TDB	2002/02/01 12 20
-	83	("257/493").CCLS.	USPAT;	2002/02/01 13:39
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	64	("438/212").CCLS.	USPAT;	2002/02/01 13:39
		(130/212).0010.	US-PGPUB;	2002/02/01 13:39
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	193	("438/259").CCLS.	USPAT;	2002/02/01 13:39
			US-PGPUB;	1002,02,01
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	1391	("438/270").CCLS.	USPAT;	2002/02/01 13:40
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	321	("438/271").CCLS.	USPAT;	2002/02/01 13:40
			US-PGPUB;	
			EPO; JPO;	
•			DERWENT;	
			IBM TDB	
-	231	("438/587").CCLS.	USPAT;	2002/02/01 13:40
	-		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
]	/# 420 /500 # : ====	IBM TDB	
-	141	("438/588").CCLS.	USPAT;	2002/02/01 13:40
			US-PGPUB;	
1			EPO; JPO;	
1			DERWENT;	
	205	/"/30/500"\ CCT C	IBM TDB	2000/00/01 10 10
	205	("438/589").CCLS.	USPAT;	2002/02/01 13:40
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
-	0	("L1 or L2 or L3 or L4 or L5 or L6 or L7	USPAT;	2002/02/01 13:40
E .	Ĭ	or L8 or L9 or L10").PN.	US-PGPUB;	2002/02/01 13:40
		OF TO OF THE PARTY.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	3400	(("257/401").CCLS.) or (("257/135").CCLS.)	USPAT;	2002/02/01 13:50
	_ <i></i> -	or (("257/491").CCLS.) or	US-PGPUB;	, 52, 52 15.56
		(("257/492").CCLS.) or (("257/493").CCLS.)	EPO; JPO;	
		or (("438/212").CCLS.) or	DERWENT;	
:		(("438/259").CCLS.) or (("438/270").CCLS.)	IBM TDB	
		or (("438/271").CCLS.) or		
		(("438/587").CCLS.)		
-	274		USPAT;	2002/02/01 13:53
		(("257/135").CCLS.) or (("257/491").CCLS.)	US-PGPUB;	
		or (("257/492").CCLS.) or	EPO; JPO;	
		(("257/493").CCLS.) or (("438/212").CCLS.)	DERWENT;	
		or (("438/259").CCLS.) or	IBM TDB	
		(("438/270").CCLS.) or (("438/271").CCLS.)		
		or (("438/587").CCLS.)) and ((groove or		
		trench) near15 insulat\$3 adj2 (layer or		
		film))		

			HCDATT.	2002/02/01 13:54
-	329	((("257/401").CCLS.) or	USPAT;	2002/02/01 13:34
		(("257/135").CCLS.) or (("257/491").CCLS.)	US-PGPUB; EPO; JPO;	
		or (("257/492").CCLS.) or		
		(("257/493").CCLS.) or (("438/212").CCLS.)	DERWENT; IBM TDB	
		or (("438/259").CCLS.) or	TOM IND	
		(("438/270").CCLS.) or (("438/271").CCLS.)		
		or (("438/587").CCLS.)) and (groove or		
		trench) adj2 gate	USPAT;	2002/02/01 13:56
_	81	(((("257/401").CCLS.) or	US-PGPUB;	2002, 02, 02
		(("257/135").CCLS.) or (("257/491").CCLS.)	EPO; JPO;	
		or (("257/492").CCLS.) or (("257/493").CCLS.) or (("438/212").CCLS.)	DERWENT;	
		or (("438/259").CCLS.) or	IBM TDB	
		(("438/270").CCLS.) or (("438/271").CCLS.)		
		or (("438/587").CCLS.)) and (groove or		
:		trench) adj2 gate) and base adj2 (region		
		or layer)		1
_	81	(((("257/401").CCLS.) or	USPAT;	2002/02/01 14:31
		(("257/135").CCLS.) or (("257/491").CCLS.)	US-PGPUB;	
		or (("257/492").CCLS.) or	EPO; JPO;	
		(("257/493").CCLS.) or (("438/212").CCLS.)	DERWENT;	
		or (("438/259").CCLS.) or	IBM TDB	
		(("438/270").CCLS.) or (("438/271").CCLS.)		
		or (("438/587").CCLS.)) and (groove or		
		trench) adj2 gate) and (n-base or p-base		
		or p adj base or n adj base or base) adj2		
		(region or layer)	USPAT;	2002/02/01 14:38
–	24	hamada.in. and trench	US-PGPUB;	2002/02/01 14:30
			EPO; JPO;	
	E		DERWENT;	
			IBM TDB	
	2074	(()	EPO; JPO;	2002/02/01 14:39
-	3071	((trench or groove) near3 gate)	DERWENT;	2002, 02, 02
			IBM TDB	
	620	((trench or groove) near3 gate) and	EPO; JPO;	2002/02/01 14:40
-	629	conduct\$5 and semiconduct\$5	DERWENT;	
		Conductas and semiconductas	IBM TDB	
	612	((trench or groove) near3 gate) and	EPO; JPO;	2002/02/01 14:40
-	012	conduct\$5 and semiconduct\$5.ti,ab.	DERWENT;	
		Conducto and being of the conductor of t	IBM TDB	
_	598	((trench or groove) near3 gate).ti,ab. and	EPO; JPO;	2002/02/01 14:49
		conduct\$5 and semiconduct\$5.ti,ab.	DERWENT;	
			IBM TDB	
_	120	((trench or groove) near3 gate).ti,ab. and	EPO; JPO;	2002/02/01 15:51
		conduct\$5 and semiconduct\$5.ti,ab. and	DERWENT;	
		connect\$3	IBM TDB	2002/02/07 11:25
_	1	5861649.pn.	USPAT	2002/02/07 11:35
_	1	6118150.pn.	EPO; JPO;	2002/02/01 15:12
			DERWENT;	
			IBM TDB	2002/02/01 15:12
-	1	6118150.pn.	USPAT EPO; JPO;	2002/02/01 15:12
_	3	herzer.in. and trench	DERWENT;	2002/02/01 10.31
			IBM TDB	
		//UC1C2OF1U\ /UC11O1EOU\	USPAT;	2002/02/01 17:24
_	8		US-PGPUB;	2002,02,01 2,021
		("6072214")).PN.	EPO; JPO;	
			DERWENT;	
†			IBM TDB	
		(("6163051") or ("6118150") or	USPAT	2002/02/01 17:25
_	3	("6072214")).PN.		
!	1	6096608.pn.	USPAT	2002/02/07 11:43
_	1	5648670.pn.	USPAT	2002/02/07 11:36
_		6163051.pn.	USPAT	2002/02/07 11:43
		0.100001.F		